

	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	1282	349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 15:24
2	BRS	1234	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) and substrate and electrode and switch\$4 and ((source and gate) near4 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:29
3	BRS	747	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) and substrate and electrode and switch\$4 and ((source and gate) near4 line) and terminal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:29
4	BRS	4	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and ((pixel near3 electrode) and switch\$4 and ((source and gate) near4 line) and ((display and terminal) near5 area)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:32
5	BRS	50	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) and ((pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:32
6	BRS	35	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) and ((pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 and hole	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:36
7	BRS	33	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) and ((pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 and (contact near4 hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:52